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conduct a signal within the chuck; an intermediate member having a first surface and a second surface and the intermediate member including: an electrical coupling adjacent the first surface and configured to couple with the electrical coupling of the chuck; an electrical coupling adjacent the second surface; and an electrical interconnect configured to connect the electrical coupling adjacent the first surface and the electrical coupling adjacent the second surface; and an electronic device workpiece configured to couple with the second surface of the intermediate member, the electronic device workpiece including a sensor and an electrical coupling configured to provide electrical connection of the sensor with the electrical coupling of the second surface of the intermediate member.--.

In the Claims

Please replace the claims with the following clean version of the entire set of pending claims, in accordance with 37 C.F.R. § 1.121(c)(1)(I).

A marked up version showing amendments to any claims being changed is provided in one or more accompanying pages separate from this amendment in accordance with 37 C.F.R. § 1.121(c)(1)(ii).

- 1. Canceled.
- 2. Canceled.
- 3. Canceled.
- 4. Canceled.
- Canceled.
- 6. Canceled.
- 7. Canceled.
- 8. Canceled.

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- 9. Canceled.
- 10. Canceled.
- 11. Canceled.
- 12. Canceled.
- 13. Canceled.
- 14. Canceled.
- 15. Canceled.
- 16. Canceled.
- 17. Canceled.
- 18. Canceled.
- 19. Canceled.
- 20. Canceled.
- 21. Canceled.
- 22. Canceled.
- 23. Canceled.
- 24. Canceled.
- 25. Canceled.
- 26. Canceled.
- 27. Canceled.
- 28. Canceled.
- 29. Canceled.
- 30. Canceled.
- 31. Canceled.
- 32. Canceled.
- 33. Canceled.
- 34. Canceled.
- 35. Canceled.
- 36. Canceled.
- 37. Canceled.

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- 38. Canceled.
- 39. Canceled.
- 40. Canceled.
- 41. Canceled.
- 42. Canceled.
- 43. Canceled.
- 44. Canceled.
- 45. Canceled.
- 46. Canceled.
- 47. Canceled.
- 48. Canceled.
- 49. Canceled.
- 50. Canceled.
- 51. Canceled.
- 52. Canceled.

53. A method of processing-a-wafer-comprising:

receiving a wafer within a workpiece processing apparatus;

supporting the wafer using a workpiece holder of the workpiece processing apparatus;

coupling circuitry of the wafer with circuitry of the workpiece holder;

processing the wafer within the workpiece processing apparatus to form at least one semiconductor device; and

communicating signals intermediate the circuitry of the wafer and the circuitry of the workpiece holder.

- 54: (Amended) The method in accordance with claim 53 wherein the coupling comprises coupling the circuitry of the wafer and the circuitry of the workpiece holder at a surface of the wafer and a surface of the workpiece holder.
- 55. The method in accordance with claim 53 wherein the receiving comprises receiving a semiconductive wafer.
- 56. The method in accordance with claim 53 further comprising altering the processing responsive to the communicating.
- 57. The method in accordance with claim 53 wherein the communicating comprises communicating during the processing.
- 58. The method in accordance with claim 53 further comprising communicating the signals using an intermediate member of the workpiece processing apparatus.,
- 59. The method in accordance with claim 53 wherein the coupling comprises contacting the circuitry of the wafer and the circuitry of the workpiece holder.

60. A method of processing a workpiece comprising:

receiving a workpiece within a workpiece processing apparatus configured to form a semiconductor device using the workpiece;

processing the workpiece within the workpiece processing apparatus to form the semiconductor device; and

communicating signals intermediate the workpiece and the workpiece processing apparatus.

- 61. The method in accordance with claim 60 further comprising electrically coupling the workpiece and the workpiece processing apparatus.
- 62. The method in accordance with claim 61 wherein the coupling comprises contacting circuitry of the workpiece and circuitry of the apparatus.
- 63. (Amended) The method in accordance with claim 60 further comprising: supporting a workpiece using a workpiece holder of the workpiece processing apparatus; and

coupling circuitry of the workpiece and circuitry of the workpiece holder at a surface of the workpiece and a surface of the workpiece holder.

64. The method in accordance with claim 60 wherein the receiving comprises receiving the workpiece comprising a semiconductive water.

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- The method-in-accordance-with-claim-60 further comprising-altering the? processing responsive to the communicating.
- The method in accordance with claim 60 wherein the communicating 66. comprises communicating during the processing.
- The method in accordance with claim 60 further comprising communicating the signals using an intermediate member of the workpiece processing apparatus.
- A method of communicating signals with respect to a wafer comprising: providing a workpiece holder; supporting a wafer using the workpiece-holder; coupling circuitry of the wafer with circuitry of the workpiece holder; and communicating signals intermediate the circuitry of the wafer and the circuitry of the workpiece holder.
- The method in accordance with claim 68 wherein the providing the wafer comprises providing a semiconductive wafer.
- The method in accordance with claim 68 wherein the coupling comprises 70. coupling the circuitry of the wafer and the circuitry of the workpiece holder at a surface of the wafer and a surface of the workpiece holder.

- 71. The method in accordance with claim 68 wherein the coupling comprises contacting the circuitry of the wafer and the circuitry of the workpiece holder.
- 72. The method in accordance with claim 68 wherein the communicating comprises communicating using an intermediate member.
- 73. A method of communicating signals within a workpiece processing apparatus comprising:

providing a workpiece processing apparatus adapted to process a workpiece to form a semiconductor device;

providing a workpiece within the workpiece processing apparatus;
communicating signals using the workpiece; and
receiving the signals within the workpiece processing apparatus from the workpiece.

- 74. The method in accordance with claim 73 further comprising coupling circuitry of the workpiece with circuitry of the workpiece processing apparatus.
- 75. The method in accordance with claim 74 wherein the coupling comprises contacting the circuitry of the workpiece with the circuitry of the workpiece processing apparatus.

- 76. The method in accordance with claim 74 further comprising breaking the coupling of the circuitry of the workpiece and the circuitry of the workpiece processing apparatus.
- 77. The method in accordance with claim 73 further comprising supporting the workpiece within the workpiece processing apparatus using a workpiece holder, and wherein the receiving comprises receiving using the workpiece holder.
- 78. (Amended) The method in accordance with claim 77 further comprising coupling circuitry of the workpiece and circuitry of the workpiece holder at a surface of the workpiece and a surface of the workpiece holder.
- 79. The method in accordance with claim 73 further comprising supporting the workpiece within the workpiece processing apparatus using a workpiece holder and an intermediate member, and wherein the receiving comprises receiving using the workpiece holder and the intermediate member.
- 80. The method in accordance with claim 73 wherein the providing the workpiece comprises providing a semiconductive wafer.
- 81. (New) The method in accordance with claim 53 wherein the communicating comprises communicating the signals comprising information.

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- 82. (New) The method in accordance with claim 53 wherein the communicating comprises communicating the signals comprising information regarding the processing.
- 83. (New) The method in accordance with claim 60 wherein the communicating comprises communicating the signals comprising information.
- 84. (New) The method in accordance with claim 60 wherein the communicating comprises communicating the signals comprising information regarding the processing.
- 85. (New) The method in accordance with claim 68 wherein the communicating comprises communicating the signals comprising information.
- 86. (New) The method in accordance with claim 68 wherein the communicating comprises communicating the signals comprising information regarding processing of the wafer.
- 87. (New) The method in accordance with claim 73 wherein the communicating comprises communicating the signals comprising information.
- 88. (New) The method in accordance with claim 73 wherein the communicating comprises communicating the signals comprising information regarding processing of the workpiece.